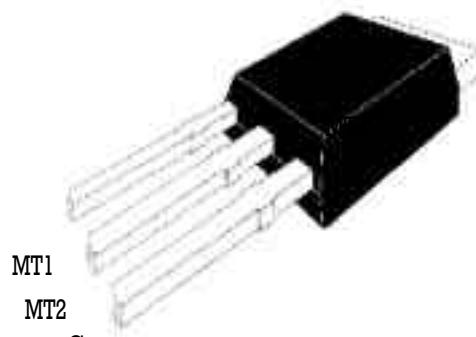


## LOGIC LEVEL TRIAC

<b>IPAK (Plastic)</b>  <p>MT1 MT2 G</p>	<b>On-State Current</b> 4 Amp	<b>Gate Trigger Current</b> < 5 mA to < 10 mA
	<b>Off-State Voltage</b> 200 V ÷ 600 V	
This series of <b>TRIACs</b> uses a high performance PNPN technology.  These parts are intended for general purpose applications where logic compatible gate sensitivity is required, like touch dimmers, fan, electrovalve control.		

### Absolute Maximum Ratings, according to IEC publication No. 134

SYMBOL	PARAMETER	CONDITIONS	Min.	Max.	Unit
$I_{T(RMS)}$	RMS On-state Current	All Conduction Angle, $T_c = 110^\circ C$	4		A
$I_{TSM}$	Non-repetitive On-State Current	Half Cycle, 60 Hz	31		A
$I_{TSM}$	Non-repetitive On-State Current	Half Cycle, 50 Hz	30		A
$I^{2t}$	Fusing Current	$t_p = 10 \text{ ms}$ , Half Cycle	5.1		A <sup>2</sup> s
$I_{GM}$	Peak Gate Current	20 $\mu\text{s}$ max.		4	A
$P_{GM}$	Peak Gate Dissipation	20 $\mu\text{s}$ max.		3	W
$P_{G(AV)}$	Gate Dissipation	20 ms max.		1	W
$di/dt$	Critical rate of rise of on-state current	$I_G = 2 \times I_{GT} \text{ Tr } 100 \text{ ns}, F = 120 \text{ Hz}$ $T_j = 125^\circ C$	50		A/ $\mu\text{s}$
$T_j$	Operating Temperature		-40	+125	°C
$T_{stg}$	Storage Temperature		-40	+150	°C
$T_{sld}$	Soldering Temperature	4.5 mm from case, 10s max.		260	°C

SYMBOL	PARAMETER	VOLTAGE			Unit
		B	D	M	
$V_{DRM}$	Repetitive Peak Off State Voltage	200	400	600	V
$V_{RRM}$					

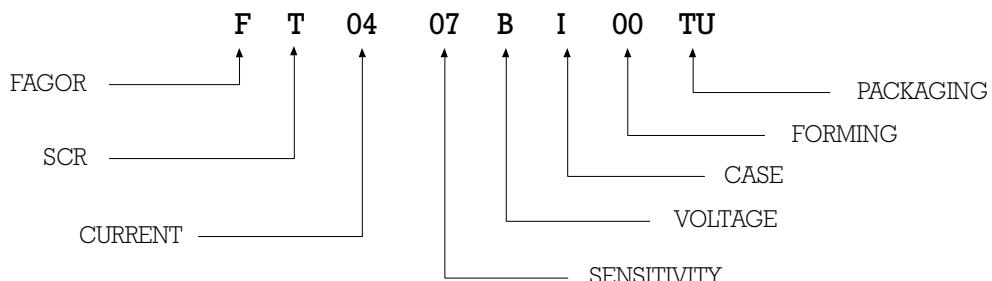
## LOGIC LEVEL TRIAC

## Electrical Characteristics

SYMBOL	PARAMETER	CONDITIONS	Quadrant	SENSITIVITY		Unit
				07	08	
$I_{GT}$	Gate Trigger Current	$V_D = 12 \text{ V}_{DC}$ , $R_L = 30 \Omega$ , $T_j = 25^\circ\text{C}$	Q1÷Q3 Q4	MAX MAX	5 7	mA
$I_{DRM} / I_{RRM}$	Off-State Leakage Current	$V_D = V_{DRM}$ , $V_R = V_{RRM}$ , $T_j = 125^\circ\text{C}$ , $T_j = 25^\circ\text{C}$		MAX MAX	1 5	mA $\mu\text{A}$
$V_{to}$	Threshold Voltage	$T_j = 125^\circ\text{C}$		MAX	0.9	V
$R_d$	Dynamic Resistance	$T_j = 125^\circ\text{C}$		MAX	120	m
$V_{TM}^*$	On-state Voltage	$I_T = 5.5 \text{ Amp}$ , $t_p = 380 \mu\text{s}$ , $T_j = 25^\circ\text{C}$		MAX	1.6	V
$V_{GT}$	Gate Trigger Voltage	$V_D = 12 \text{ V}_{DC}$ , $R_L = 30 \Omega$ , $T_j = 25^\circ\text{C}$	Q1÷Q3	MAX	1.3	V
$V_{GD}$	Gate Non Trigger Voltage	$V_D = V_{DRM}$ , $R_L = 3.3\text{K}$ , $T_j = 125^\circ\text{C}$	Q1÷Q3	MIN	0.2	V
$I_H^*$	Holding Current	$I_T = 100 \text{ mA}$ , Gate Open $T_j = 25^\circ\text{C}$		MAX	10 15	mA
$I_L$	Latching Current	$I_G = 1.2 I_{GT}$ , $T_j = 25^\circ\text{C}$	Q1,Q3,Q4 Q2	MAX MAX	10 15 20 30	mA
$dv / dt^*$	Critical Rate of Voltage Rise	$V_D = 0.67 \times V_{DRM}$ , Gate open $T_j = 125^\circ\text{C}$		MIN	20 100	V/ $\mu\text{s}$
$R_{th(j-c)}$	Thermal Resistance Junction-Case for AC				2.6	$^\circ\text{C/W}$
$R_{th(j-a)}$	Thermal Resistance Junction-Ambient				100	$^\circ\text{C/W}$

(\*) For either polarity of electrode MT2 voltage with reference to electrode MT1.

## PART NUMBER INFORMATION



## LOGIC LEVEL TRIAC

Fig. 1: Maximum RMS power dissipation versus RMS on-state current.

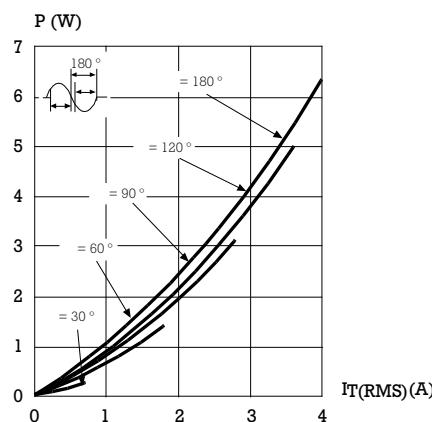


Fig. 2: Correlation between maximum RMS power dissipation and maximum allowable temperature (Tamb and T case).

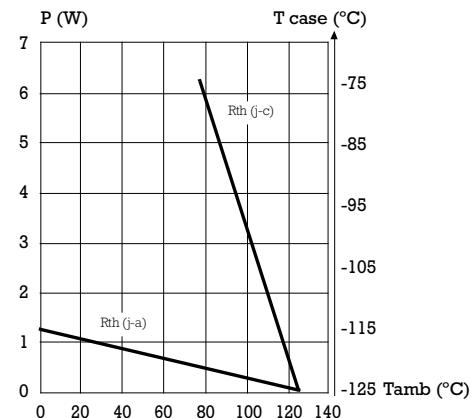


Fig. 3: RMS on-state current versus case temperature.

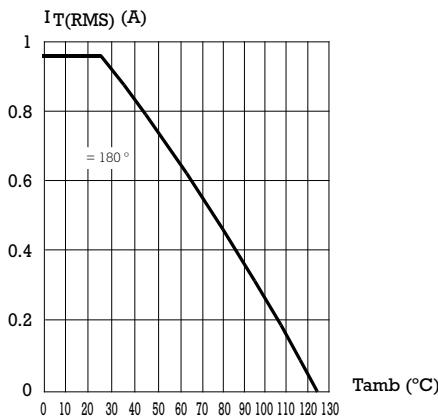


Fig. 4: Relative variation of thermal impedance junction to ambient versus pulse duration.

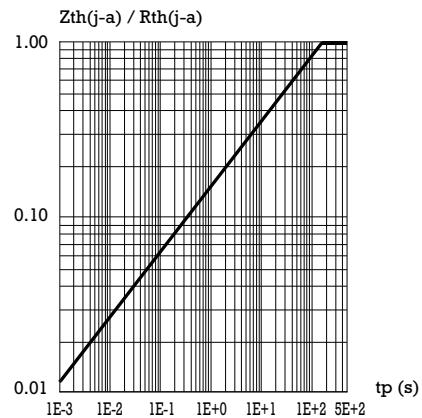


Fig. 5: Relative variation of gate trigger current and holding current versus junction temperature.

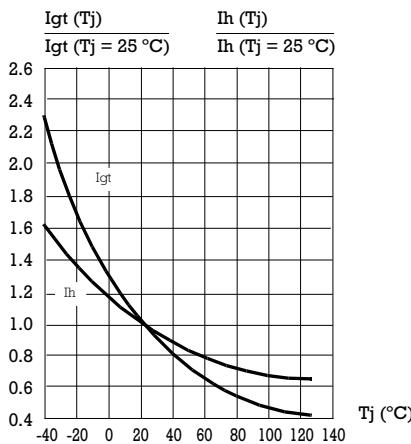
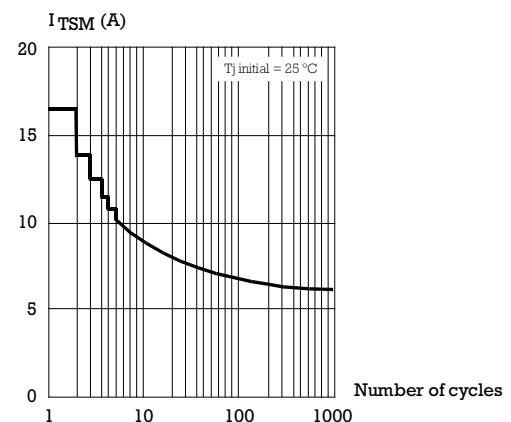


Fig. 6: Non repetitive surge peak on-state current versus number of cycles.



## LOGIC LEVEL TRIAC

Fig. 7: Non repetitive surge peak on-state current for a sinusoidal pulse with width:  $t_p = 10 \text{ ms}$ , and corresponding value of  $I^2 t$ .

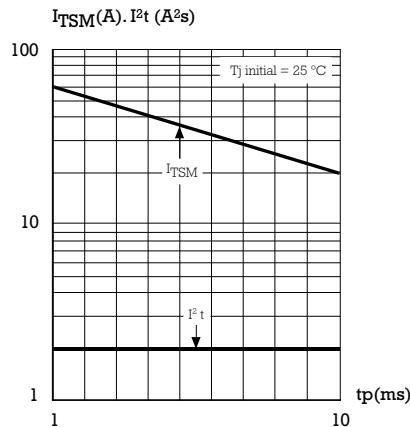
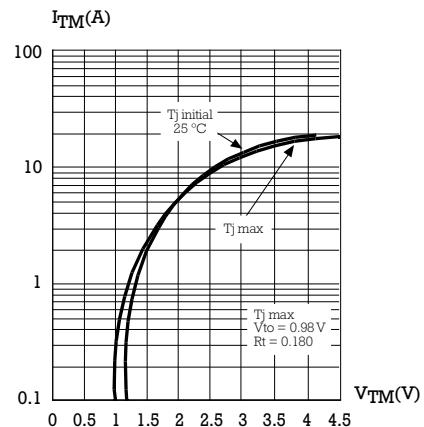


Fig. 8: On-state characteristics (maximum values).



## PACKAGE MECHANICAL DATA IPAK TO 251-AA

REF.	DIMENSIONS		
	Milimeters		
	Min.	Nominal	Max.
A	2.19	$2.3 \pm 0.08$	2.38
Al	0.89	$1.067 \pm 0.01$	1.14
b	0.64	$0.75 \pm 0.1$	0.89
b1	0.76	0.95	1.14
c	0.46		0.58
c2		$0.8 \pm 0.013$	
D	5.97	$6.1 \pm 0.1$	6.22
D1	5.21		5.52
E	6.35	$6.58 \pm 0.14$	6.73
E1	5.21	$5.36 \pm 0.1$	5.46
e		2.28BSC	
L	8.89	$9.2 \pm 0.2$	9.65
L1	1.91	$2 \pm 0.1$	2.28
L3	0.89		1.27

Marking: type number  
Weight: 0.2 g